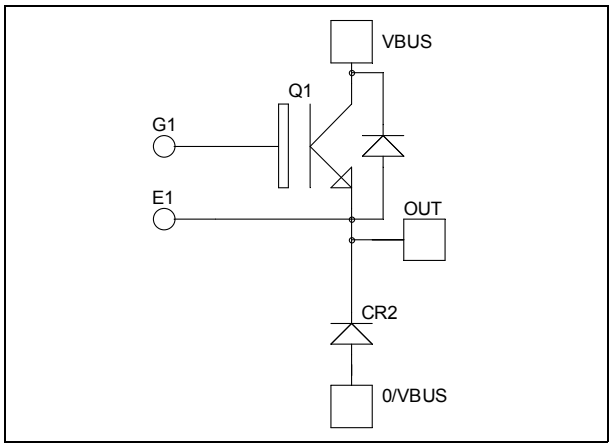
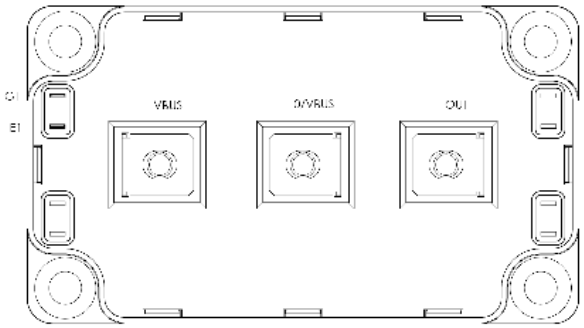
APTGLQ300SK120G

Buck chopper
High speed Trench + Field Stop
IGBT4 Power module

V_{CES} = 1200V
I_C = 300A @ Tc = 80°C





Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- **High speed Trench + Field Stop IGBT 4**
  - Low voltage drop
  - Low leakage current
  - Low switching losses
- Kelvin emitter for easy drive
- Very low stray inductance
- M5 power connectors

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS compliant

All ratings @ T_j = 25°C unless otherwise specified

Absolute maximum ratings

Symbol	*Parameter*		*Max ratings*	*Unit*
V_{CES}	Collector - Emitter Voltage		1200	V
I_C	Continuous Collector Current	T_C = 25°C	500	A
		T_C = 80°C	300	
I_{CM}	Pulsed Collector Current	T_C = 25°C	960	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation		1500	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	V_{GE} = 0V, V_{CE} = 1200V				200	µA
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	V_{GE} =15V I_C = 300A	T_j = 25°C	1.78	2.05	2.42	V
			T_j = 150°C		2.6		
$V_{GE(th)}$	Gate Threshold Voltage	V_{GE} = V_{CE} , I_C = 10.4 mA		5.3	5.8	6.3	V
I_{GES}	Gate – Emitter Leakage Current	V_{GE} = 20V, V_{CE} = 0V				480	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
C_{ies}	Input Capacitance	V_{GE} = 0V V_{CE} = 25V f = 1MHz			17.6		nF
C_{oes}	Output Capacitance				1		
C_{res}	Reverse Transfer Capacitance				0.9		
Q_G	Gate charge	V_{GE} = 15V, I_C = 300A V_{CE} = 960V			1290		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) V_{GE} = ±15V V_{Bus} = 600V I_C = 300A R_G = 1.6Ω			30		ns
T_r	Rise Time				57		
$T_{d(off)}$	Turn-off Delay Time				290		
T_f	Fall Time				16		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) V_{GE} = ±15V V_{Bus} = 600V I_C = 300A R_G = 1.6Ω			30		ns
T_r	Rise Time				49		
$T_{d(off)}$	Turn-off Delay Time				366		
T_f	Fall Time				48		
E_{on}	Turn on Energy	V_{GE} = ±15V V_{Bus} = 600V I_C = 300A R_G = 1.6Ω	T_j = 150°C		26		mJ
E_{off}	Turn off Energy		T_j = 150°C		16		
R_G	Integrated gate resistor				2.5		Ω
I_{sc}	Short Circuit data	V_{GE} ≤15V ; V_{Bus} = 600V t_p≤10µs ; T_j = 150°C			1000		A
R_{thJC}	Junction to Case Thermal Resistance					0.1	°C/W

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	V_R=1200V				400	µA
I_F	DC Forward Current		Tc = 80°C		400		A
V_F	Diode Forward Voltage	I_F = 400A			2.4	3.5	V
		I_F = 600A			2.7		
		I_F = 400A	T_j = 125°C		1.8		
t_{rr}	Reverse Recovery Time	I_F = 400A V_R = 800V di/dt =800A/µs	T_j = 25°C		385		ns
			T_j = 125°C		480		
Q_{rr}	Reverse Recovery Charge		T_j = 25°C		4.2		µC
			T_j = 125°C		21		
R_{thJC}	Junction to Case Thermal Resistance					0.096	°C/W

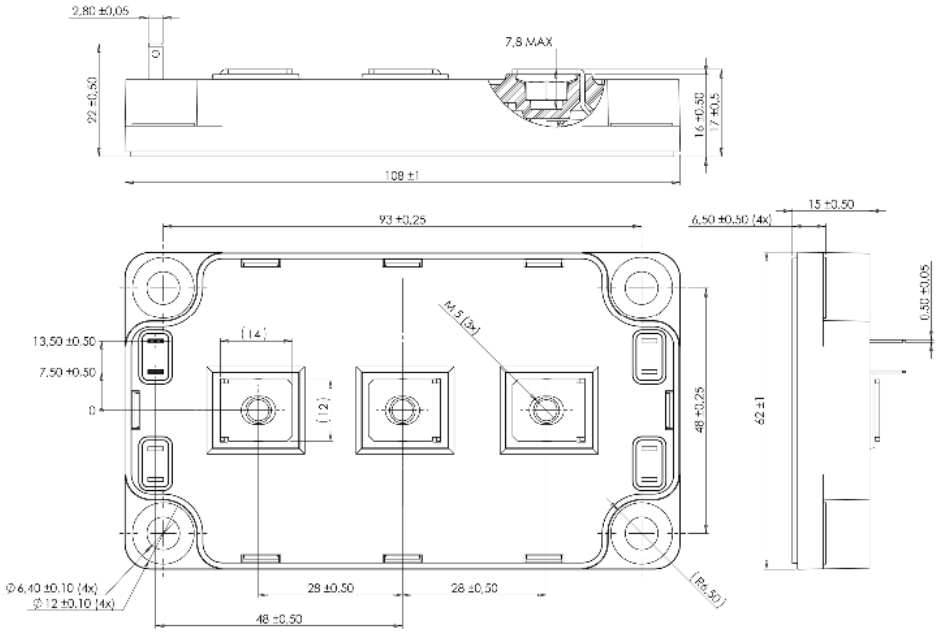
IGBT parallel diode ratings and characteristics

Symbol	*Characteristic*	*Test Conditions*		*Min*	*Typ*	*Max*	*Unit*
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	V_R=1200V				100	µA
I_F	DC Forward Current		Tc = 70°C		30		A
V_F	Diode Forward Voltage	I_F = 30A			2.6	3.5	V
		I_F = 60A			3.2		
		I_F = 30A	T_j = 125°C		1.8		
t_{rr}	Reverse Recovery Time	I_F = 30A V_R = 800V di/dt =200A/µs	T_j = 25°C		300		ns
			T_j = 125°C		360		
Q_{rr}	Reverse Recovery Charge		T_j = 25°C		360		nC
			T_j = 125°C		1700		
R_{thJC}	Junction to Case Thermal Resistance					1.2	°C/W

Thermal and package characteristics

Symbol	*Characteristic*			*Min*	*Max*	*Unit*
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
T_J	Operating junction temperature range			-40	175	°C
T_{JOP}	Recommended junction temperature under switching conditions			-40	$T_J$max -25	
T_{STG}	Storage Temperature Range			-40	125	
T_C	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight				300	g

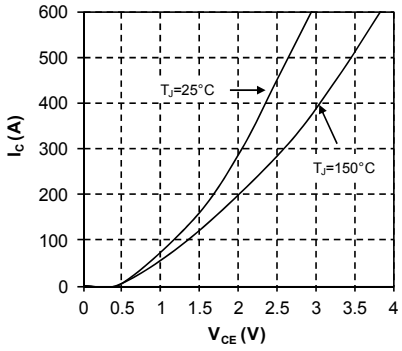
Package outline (dimensions in mm)



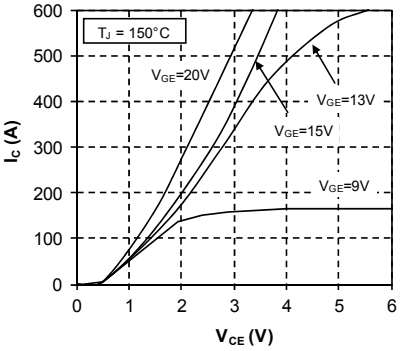
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical IGBT & chopper diode Performance Curve

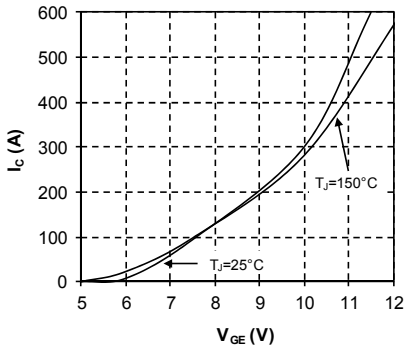
Output Characteristics (V_{GE}=15V)



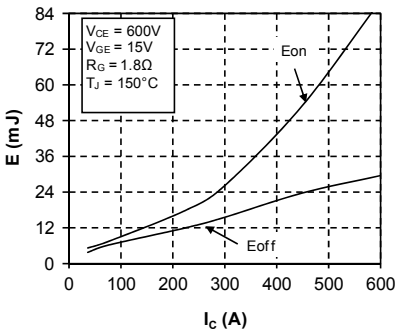
Output Characteristics



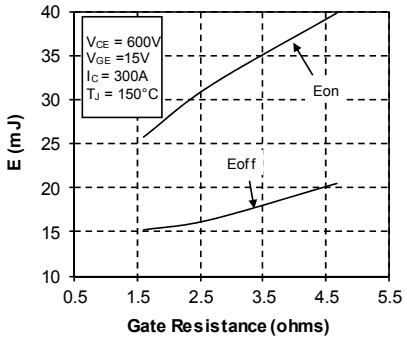
Transfert Characteristics



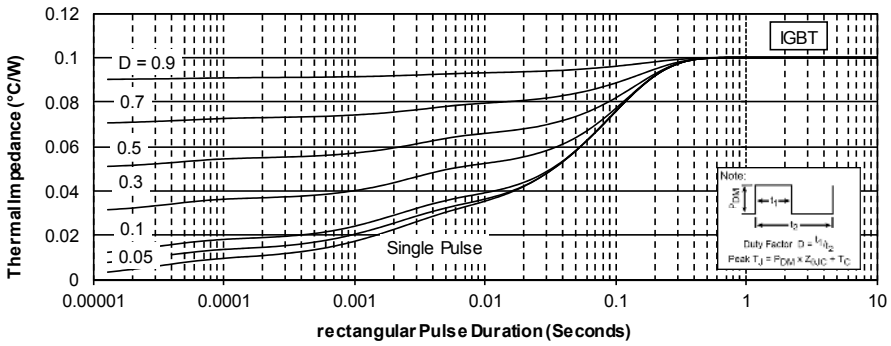
Energy losses vs Collector Current

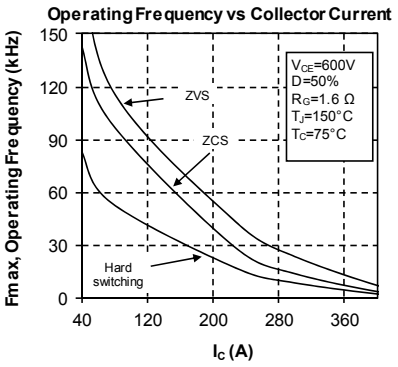


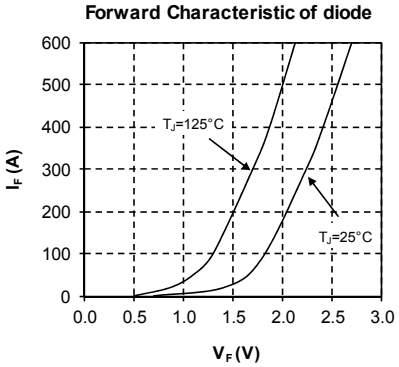
Switching Energy Losses vs Gate Resistance

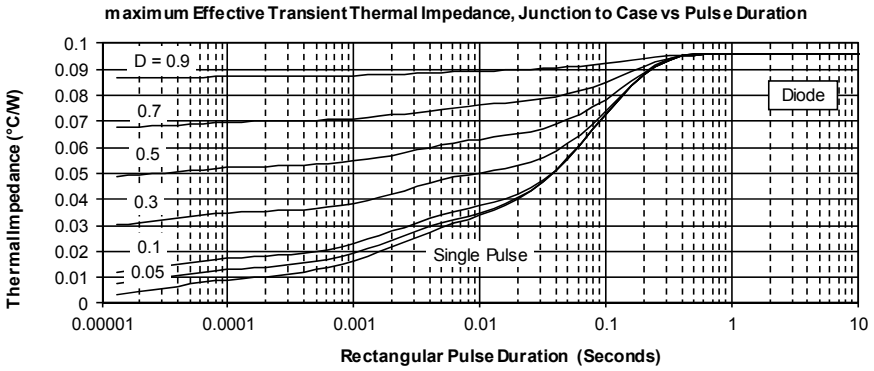


maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration

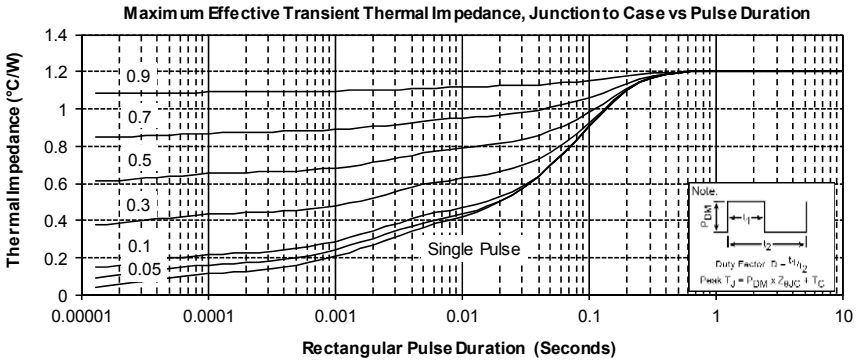


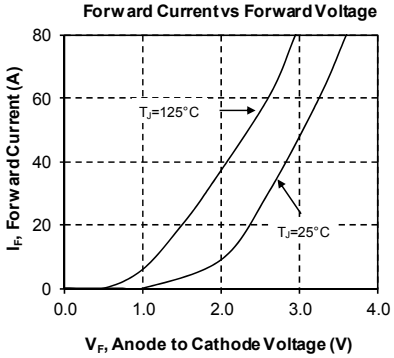






IGBT parallel diode Typical Performance Curve





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